

STAP16DPPS05

Automotive-grade low voltage 16-bit constant current LED sink driver with output error detection and auto power-saving

Datasheet - production data



Features



- AECQ100 qualified
- Low voltage power supply down to 3 V
- 16 constant current output channels
- Adjustable output current through external resistor
- Short and open output error detection
- Serial data IN/parallel data OUT
- 3.3 V micro driver-able
- Auto power-saving
- Output current: 3 40 mA
- Auto power-saving
- Max. clock frequency: 30 MHz
- 20 V current generator rated voltage
- Power supply voltage: from 3 V to 5.5 V
- Thermal shutdown for overtemperature protection
- ESD protection 2.0 KV HBM

Applications

- Dashboard and infotainment backlighting
- Exterior/interior lighting
- DTRLs

Description

The STAP16DPPS05 is a monolithic, low voltage, low current power 16-bit shift register

designed for LED panel displays. The device contains a 16-bit serial-in, parallel-out shift register that feeds a 16-bit D-type storage register. In the output stage, sixteen regulated current sources are designed to provide 3 to 40 mA of constant current to drive the LEDs.

The STAP16DPPS05 features the open and short LED detection on the outputs. The detection circuit checks 3 different conditions which may occur on the output line: short to GND, short to Vo or open line. The data detection results are loaded in the shift register and shifted out via the serial line output. The detection functionality is implemented without increasing the pin number through a secondary function of the output enable and latch pin (DM1 and DM2) respectively). A dedicated logic sequence allows the device to enter or leave detection mode. Through an external resistor, users can adjust the output current of the STP16DPPS05 thus controlling the light intensity of the LEDs. In addition, the user can adjust the intensity of the brightness of the LED's from 0 % to 100 %

through the OE/DM2 pin. The auto power shutdown and auto power-ON feature allows the device to save power with no external intervention. The STAP16DPPS05 guarantees a 20 V output driving capability, allowing users to connect more LEDs in series. The high clock frequency, 30 MHz also satisfies the system requirement of high volume data transmission. The 3.3 V of voltage supply is very useful for applications interfacing any microcontroller from 3.3 V micro. Compared with a standard TSSOP package, the TSSOP exposed pad increases the capability of heat dissipation by a factor of 2.5.

Table 1: Device summary

Order code	Package	Packing	
STAP16DPPS05XTTR	TSSOP24 (exposed pad)	2500 parts per reel	

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This is information on a product in full production.

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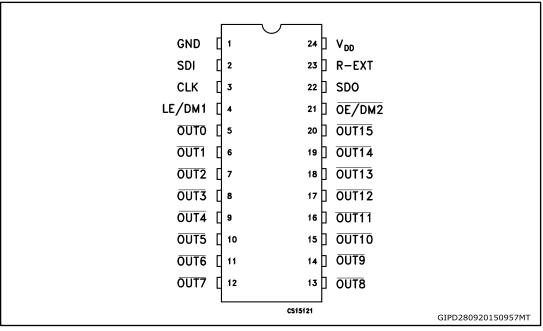
1 Summary description

Table 2: Typical current accuracy

Output valtage		Current accuracy		Quitnut ourrent	V _{DD}	Temperature	
	Output voltage	Between bits	Between ICs	Output current	V DD	remperature	
	≥ 1.3 V	± 1 %	±2%	5 to 40 mA	3.3 V to 5 V	25 °C	

1.1 Pin connections and description

Figure 1: Pin connection





The exposed pad is electrically connected to a metal layer electrically isolated or connected to ground.

Table 3: Pin description

Pin n°	Symbol	Name and function
1	GND	Ground terminal
2	SDI	Serial data input terminal
3	CLK	Clock input terminal
4	LE/DM1	Latch input terminal - detect mode 1 (see operation principle)
5-20	OUT-15	Output terminal
21	OE/DM2	Input terminal of output enable (active low) - detect mode 1 (see operation principle)
22	SDO	Serial data out terminal
23	R-EXT	Input terminal for an external resistor for constant current programming
24	V_{DD}	Supply voltage terminal



Electrical ratings STAP16DPPS05

2 Electrical ratings

2.1 Absolute maximum ratings

Stressing the device above the rating listed in the "absolute maximum ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Symbol	Parameter	Value	Unit
V_{dd}	Supply voltage	0 to 7	V
Vo	Output voltage	-0.5 to 20	V
lo	Output current	50	mA
Vı	Input voltage	-0.4 to V _{dd}	V
Ignd	GND terminal current	800	mA
f _{CLK}	Clock frequency	50	MHz
Topr	Operating temperature range	-40 to +150	°C
T _{STG}	Storage temperature range	-55 to +150	°C

2.2 Thermal data

Table 5: Thermal data

Symbol	Para	Value	Unit	
R _{thj-amb}	Thermal resistance junction-ambient (1)	TSSOP24 (exposed pad) (2)	37.5	°C/W

Notes:

⁽¹⁾According to JEDEC standard 51-7B.

⁽²⁾ The exposed pad should be soldered to the PCB in order to derive the thermal benefits.

STAP16DPPS05 Electrical ratings

2.3 Recommended operating conditions

Table 6: Recommended operating conditions

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
V _{DD}	Supply voltage		3.0	•	5.5	V
Vo	Output voltage			-	20	V
lo	Output current	OUTn	3	•	40	mA
Іон	Output current	SeriaL-OUT		•	+1	mA
loL	Output current	Serial-OUT		•	-1	mA
V _{IH}	Input voltage		0.7 V _{DD}	-	V_{DD}	V
VIL	Input voltage		-0.3	•	0.3 V _{DD}	V
t _{wLAT}	LE/DM1 pulse width		20	-		ns
twclk	CLK pulse width		10	•		ns
t _{wEN}	OE/DM2 pulse width	V _{DD} = 3.0 V to 5.0 V	100	1		ns
tsetup(d)	Setup time for DATA		8	-		ns
thold(d)	Hold time for DATA		5	•		ns
tsetup(L)	Setup time for LATCH		8	-		ns
fclk	Clock frequency	Cascade operation (1)		-	30	MHz

Notes:

 $^{^{(1)}}$ If the device is connected in cascade, it may not be possible to achieve the maximum data transfer. Please consider the timings carefully.

3 Electrical characteristics

 V_{DD} = 5 V, T_j = -40 °C to 125 °C, unless otherwise specified.

Table 7: Electrical characteristics

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
ViH	Input voltage high level		0.7·V _{DD}		V_{DD}	
V _{IL}	Input voltage low level		GND		0.3-V _{DD}	V
Vol	Serial data output voltage	$I_{OL} = + 1 \text{ mA}$		0.03	0.4	
V _{OH}	(SDO)	$I_{OH} = -1 \text{ mA}$	V _{DD} -0.4			
Іон	Output leakage current	Vo =19 V, OUTn = OFF		0.5	2	μΑ
ΔI_{OL1}		$V_{DD} = 3.3 \text{ V}, V_{O} = 0.3 \text{ V},$ $R_{\text{ext}} = 3.9 \text{ k}\Omega$		±1	±5	
∆l _{OL2}	Current accuracy channel-to-channel	$V_{DD} = 3.3 \text{ V}, V_{O} = 0.6 \text{ V},$ $R_{\text{ext}} = 980 \Omega$		±0.5	±4	
ΔІ _{ОL3}		$V_{DD} = 3.3 \text{ V}, V_{O} = 1.3 \text{ V},$ $R_{\text{ext}} = 490 \Omega$		±0.5	±4	%
Δl _{OL2}	Current accuracy device-	$V_{DD} = 3.3 \text{ V}, V_{O} = 0.6 \text{ V},$ $R_{\text{ext}} = 980 \Omega$			±5	
ΔІ _{ОL3}	to-device ⁽¹⁾	$V_{DD} = 3.3 \text{ V}, V_{O} = 1.3 \text{ V},$ $R_{\text{ext}} = 490 \Omega$			±6	
R _{IN} (up)	Pull-up resistor for OE pin		150	300	600	
R _{IN} (down)	Pull-down resistor for LE pin		100	200	400	kΩ
IDD(AutoOff)		R_{ext} = 980 Ω , OE = low, OUT0 to OUT7 = OFF		200	300	μA
IDD(OFF1)	Supply current (OFF)	R_{ext} = 980 Ω , OE = high, OUT0 to OUT7 = ON		5	7.5	
IDD(OFF2)		R_{ext} = 490 Ω , OE = high, OUT0 to OUT15 = ON		8	11	m Λ
IDD(ON1)	Supply oursest (ONI)	R_{ext} = 980 Ω , OE = low, OUT0 to OUT15 = ON		6	7.5	mA
IDD(ON2)	Supply current (ON)	R_{ext} = 490 Ω , OE = low, OUT0 to OUT15 = ON		8	11	
Tsd	Thermal shutdown ⁽³⁾			170		°C

Notes:

⁽¹⁾Test performed with all outputs turned on, but only one output loaded at a time.

 $^{^{(2)}\}Delta_{IOL}$ + = ((IoLmax - IoLmean) / IoLmean) * 100, Δ_{IOL} - = ((IoLmin - IoLmean) / IoLmean) *100, where IoLmean = (IoLout1+IoLout2+...+IoLout16) / 16.

⁽³⁾Not tested, guaranteed by design.

 $V_{DD} = 5 \text{ V}, T_j = 25 \text{ °C}, \text{ unless otherwise specified.}$

Table 8: Switching characteristics (all table limits are guaranteed by design. Not tested in production.)

Symbol	Parameter	Test condition			Тур.	Max.	Unit
f _{clk}	Clock frequency	Cascade operation				30	MHz
	CLK- OUTn ,		$V_{DD} = 3.3 \text{ V}$		55	90	
t _{PLH1}	LE/DM1 = H,				00	50	ns
	OE/DM2 = L		$V_{DD} = 5 V$		30	50	
	LE/DM1- OUTn ,		V _{DD} = 3.3 V		48	80	
t _{PLH2}	OE/DM2 = L		$V_{DD} = 5 V$		30	45	ns
	OE/DM2 - OUTn ,		V _{DD} = 3.3 V		70	120	
t _{PLH3}	LE\\DM1 = H		$V_{DD} = 5 V$		45	65	ns
4	CLK-SDO		V _{DD} = 3.3 V		21	35	200
t _{PLH}	CLK-SDO		$V_{DD} = 5 V$		15	25	ns
	CLK OUTn ,		V _{DD} = 3.3 V		28	35	
t _{PHL1}	LE/DM1 = H,	$V_{IH} = V_{DD}$ $V_{IL} = GND$ $C_{L} = C_{L}$	10 pF		22	40	ns
	OE/DM2 = L	Io = 20 mA V _L = 3	. 100 0 1				
	LE/DM1- OUTn ,	$R_L = 60 \Omega$	V _{DD} = 3.3 V		13	35	
tPHL2	OE/DM2 = L		$V_{DD} = 5 V$		12	18	ns
	OE /DM2- OUTn ,		$V_{DD} = 3.3 \text{ V}$		24	35	
t _{PHL3}	LE/DM1 = H		$V_{DD} = 5 V$		21	30	ns
4	CLK CDO		V _{DD} = 3.3 V		24	40	20
tphl	CLK-SDO		$V_{DD} = 5 V$		17	25	ns
	Output fall time		V _{DD} = 3.3 V		30	55	
ton	10~90 % of voltage waveform		$V_{DD} = 5 V$		10	20	ns
	Output rise time		$V_{DD} = 3.3 \text{ V}$		4	10	
t _{OFF}	90~10 % of voltage waveform		$V_{DD} = 5 V$		3	8	ns
tr	CLK rise time (1)					5	μs
t _f	CLK fall time ⁽¹⁾					5	μο

Notes:

⁽¹⁾If devices are connected in cascade and tr or tf is large, it may be critical to achieve the timing required for data transfer between two cascaded devices.



4 Equivalent circuit and outputs

Figure 2: OE/DM2 terminal

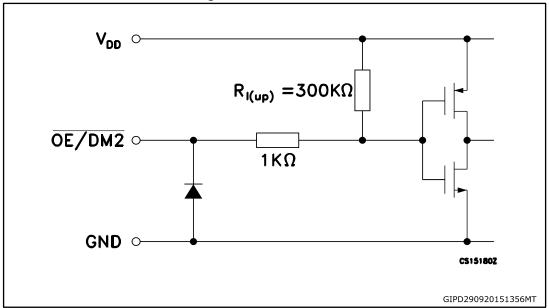
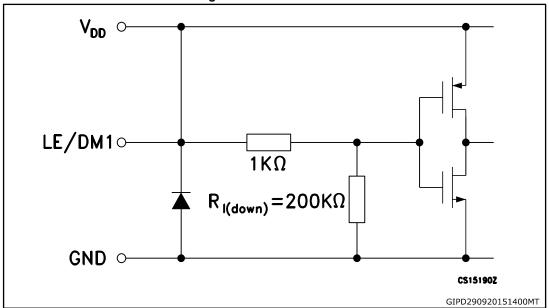


Figure 3: LE/DM1 terminal



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Figure 4: CLK, SDI terminal

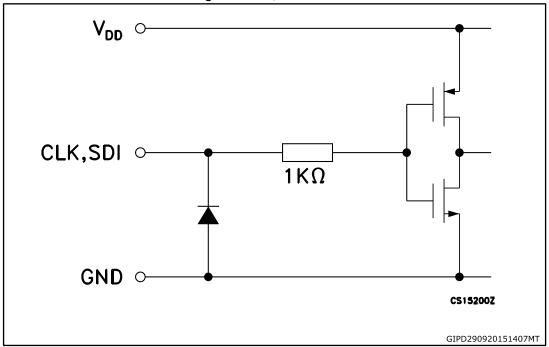
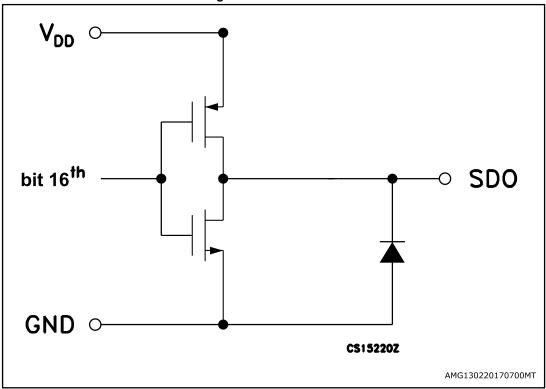


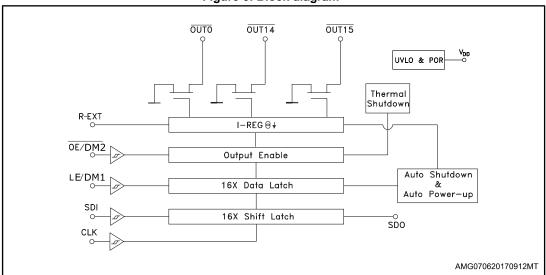
Figure 5: SDO terminal



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Figure 6: Block diagram



STAP16DPPS05 Timing diagrams

5 Timing diagrams

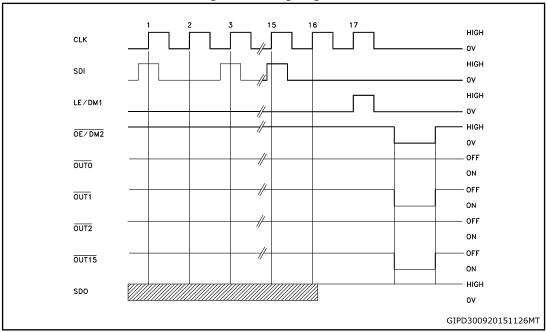
Table 9: Truth table

Clock	LE/DM1	OE/DM2	Serial-IN	OUT0OUT7	SDO
_ -	Η	L	Dn	Dn Dn - 7 Dn -15	Dn - 15
_ -	L	L	Dn + 1	No change	Dn - 14
_ -	Η	L	Dn + 2	Dn + 2 Dn - 5 Dn -13	Dn - 13
	X	L	Dn + 3	Dn + 2 Dn - 5 Dn -13	Dn - 13
- _	Х	Н	Dn + 3	OFF	Dn - 13



OUTn = ON when Dn = H OUTn = OFF when Dn = L.

Figure 7: Timing diagram





Latch and output enable terminals are level-sensitive and are not synchronized with rising or falling edge of LE/DM1 signal. When LE/DM1 terminal is low level, the latch circuit holds previous set of data. When LE/DM1 terminal is high level, the latch circuit refreshes new set of data from SDI chain. When $\overline{OE/DM2}$ terminal is at low level, the output terminals Out 0 to Out 15 respond to data in the latch circuits, either '1' ON or '0' OFF. When $\overline{OE/DM2}$ terminal is at high level, all output terminals are switched OFF.



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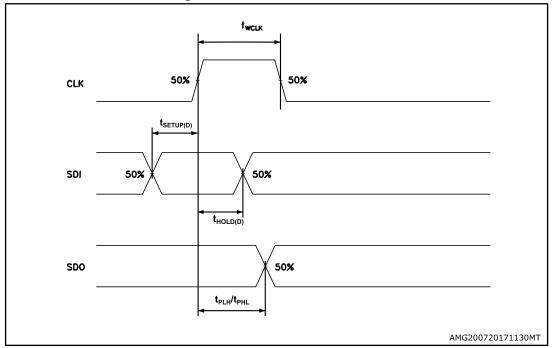
Timing diagrams STAP16DPPS05

Table 10: Enable IO: shutdown truth table

Clock	LE/DM1	SDI ₀ SDI ₇ SDI ₁₅	SH	Auto power-up	OUTn
_ -	Н	All = L	Active	Not active ⁽¹⁾	OFF
_ -	L	No change	No change	No change	No change
_ -	Н	One or more = H	Not active	Active	X ⁽²⁾

Notes:

Figure 8: Clock, serial-in, serial-out



 $[\]ensuremath{^{(1)}}\!\text{At}$ power-up, the device starts in shutdown mode.

⁽²⁾Undefined.

STAP16DPPS05 Timing diagrams



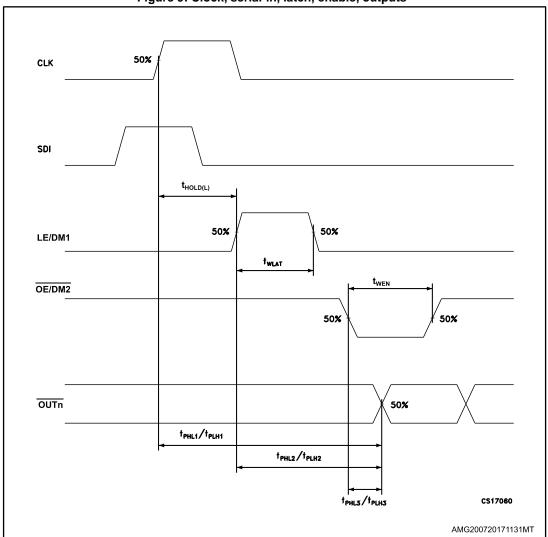
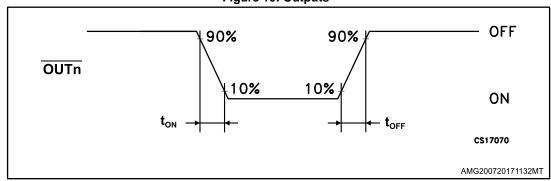


Figure 10: Outputs



6 Typical characteristics

Figure 11: Output current vs R_{EXT} resistor

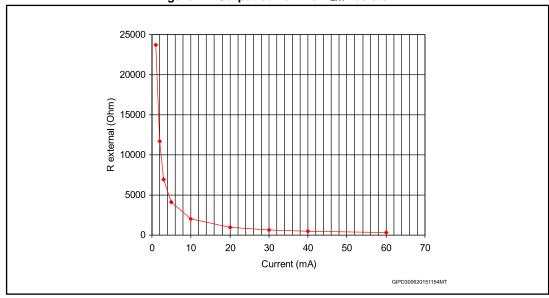


Table 11: Output current vs REXT resistor

R _{EXT} (Ω)	Output current (mA)
23700	1
11730	2
6930	3
4090	5
2025	10
1000	20
667	30
497	40
331	60

Conditions:

temperature = 25 °C, V_{DD} = 3.3 V; 5.0 V, I_{SET} = 3 mA; 5 mA; 10 mA; 20 mA; 50 mA; 60 mA.

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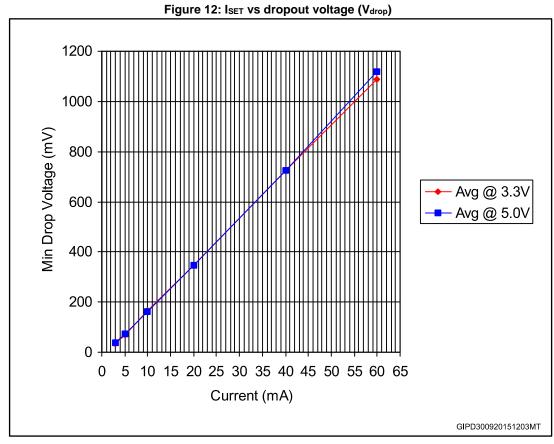


Table 12: I_{SET} vs dropout voltage (V_{drop})

	V= ,	
lout (mA)	Avg (mV) @ 3.3 V	Avg (mV) @ 5.0 V
3	36	37
5	71	72
10	163	163
20	346	347
40	724	726
60	1080	1110

 $T_A = 25 \, ^{\circ}C, \, V_{DD} = 3.3 \, V; \, 5 \, V.$

Figure 13: Output current vs ± ΔIOL(%)

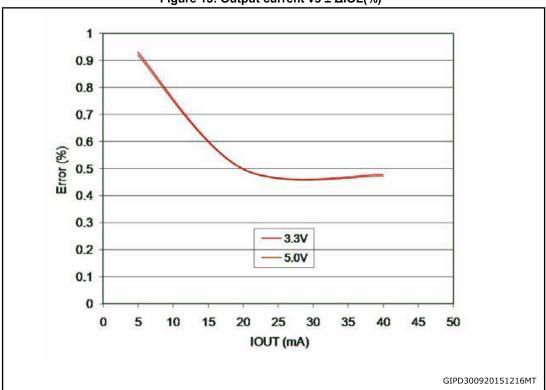
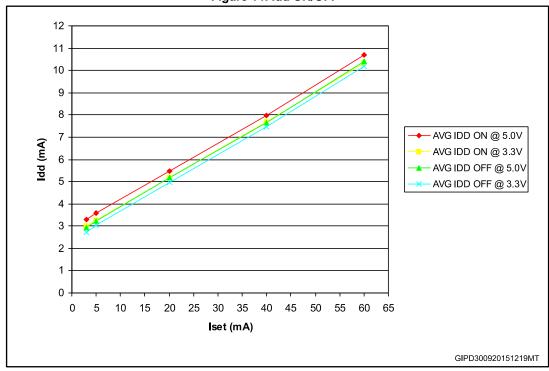


Figure 14: Idd ON/OFF



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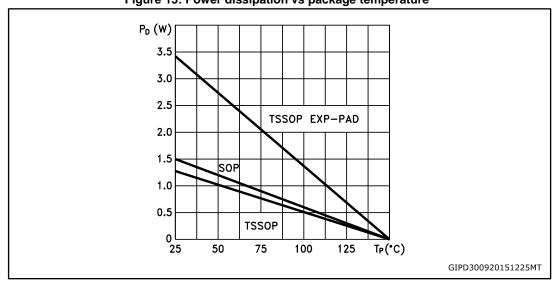
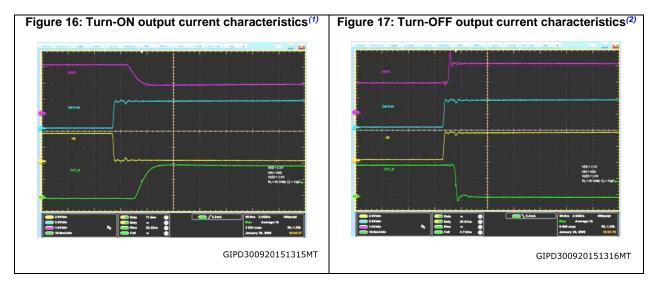


Figure 15: Power dissipation vs package temperature

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The exposed pad should be soldered to the PCB to obtain the thermal benefits.



Notes:

Electrical conditions:

- $V_{DD} = 3.3 \text{ V}$, $Vin = V_{DD}$, Vled = 3.0 V, $RL = 60 \Omega$, CL = 10 pF.
- Ch1 (yellow) = OE/DM2, Ch2 (blue) = SDI, Ch3 (purple) = VOUT, Ch4 (green) = OUT.

⁽¹⁾The reference level for the TON characteristics is 50 % of OE/DM2 signal and 90 % of output current.

⁽²⁾The reference level for the TOFF characteristics is 50 % of OE/DM2 signal and 10 % of output current.

7 Error detection mode functionality

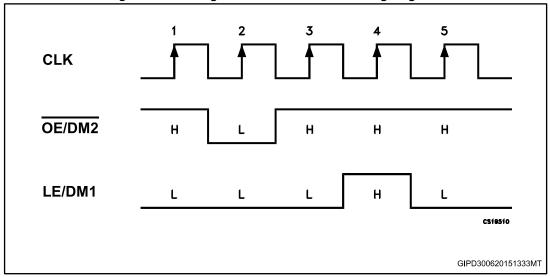
7.1 Phase one: entering error detection mode

From the "normal mode" condition the device can switch to "error mode" by a logic sequence on the $\overline{\text{OE}/\text{DM2}}$ and LE/DM1 pins, as shown in the following table and diagram:

Table 13: Entering error detection mode - truth table

CLK	1°	2°	3°	4°	5°
OE/DM2	Н	L	Н	Н	Н
LE/DM1	L	L	L	Н	L

Figure 18: Entering error detection mode - timing diagram



After these five CLK cycles, the device goes into the "error detection mode" and at the 6th rising edge of the CLK, the SDI data are ready for sampling.

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7.2 Phase two: error detection

The 16 data bits must be set to "1" in order to set ON all the outputs during detection. The data are latched by LE/DM1 and after that the outputs are ready for the detection process.

When the microcontroller switches the $\overline{\text{OE}/\text{DM2}}$ to LOW, the device drives the LEDs in order to analyze if an OPEN or SHORT condition has occurred.

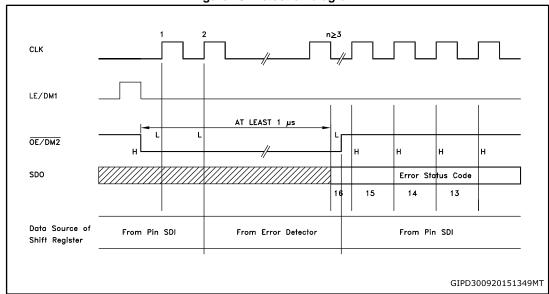


Figure 19: Detection diagram

The LED status is detected in 1 microsecond (minimum) and after this time the microcontroller sets OE/DM2 in HIGH state and the output data detection results go to the microprocessor via SDO.

Detection mode and normal mode both use the same data format. As soon as all the detection data bits are available on the serial line, the device may go back to normal mode of operation. To re-detect the status, the device must go back in normal mode and re-enter error detection mode.

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6818540 Resuming to Normal Mode Reading the Error Status Codes, Error will be represented by a "0" N x 16 CLK Pulses (2) X 14 X X 31) 30) Sending the serial Image data, all "1" to activate the OUTPUTs N x 16 CLK Pulses (1) = One more CLK pulse to fix the error status to the shift register (2) N = Number of STP160P 05 are connected in cascode pS chair CLK LE/DM1 OE/DM2 LE/DM1 OE/DM2 SDI, O Ę

Figure 20: Timing example for open and/or short-circuit detection

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7.3 Phase three: resuming normal mode

The sequence for re-entering normal mode is shown in the following table:

Table 14: Resuming normal mode - timing diagram

CLK	1°	2°	3°	4°	5°
OE/DM2	Н	L	Н	Н	Н
LE/DM1	L	L	L	L	L



For proper device operation, the "entering error detection" sequence must be followed by a "resume mode" sequence, it is not possible to insert consecutive equal sequences.

7.4 Error detection conditions

Table 15: Detection conditions (VDD = 3.3 to 5 V, temperature range -40 to 125 °C)

Configuration	Detect mode	De	tection resul	lts
SW-1 or SW-3b	Open line or output short to GND detected	==> lodec ≤ 0.5 x lo	No error detected	==> lodec ≥ 0.5 x lo
SW-2 or SW-3a	Short on LED or short to V- LED detected	==> V ₀ ≥ 2.6 V	No error detected	==> Vo ≤ 2.3 V



Where: I_0 = the output current programmed by the R_{EXT} , I_{ODEC} = the detected output current in detection mode.

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Figure 21: Detection circuit

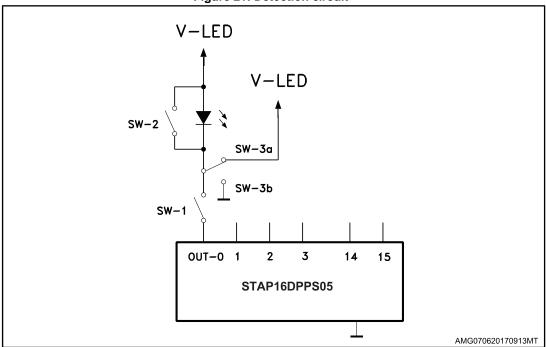
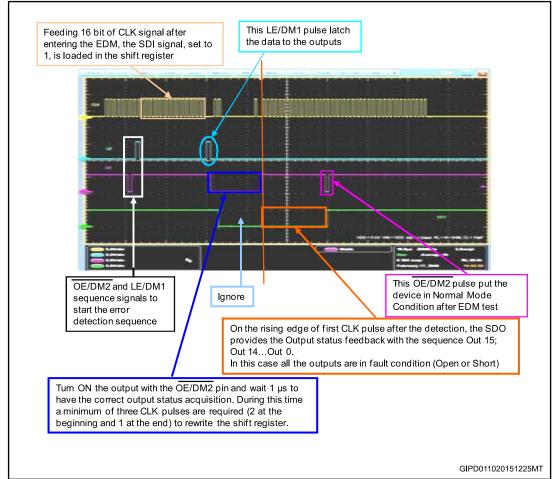


Figure 22: Error detection sequence



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7.5 Auto power-saving

The auto power-saving feature minimizes the quiescent current if no active data is detected on the latches and auto powers-up the device as the first active data is latched.

AMG070620170914MT

Figure 23: Auto power-saving feature

Conditions:

- Temp. = 25 °C, V_{DD} = 3.3 V, Vin = V_{DD}, VLed = 3.0 V, Iset = 20 mA
- Ch1 (yellow) = CLK, Ch2 (blue) = SDI, Ch3 (purple) = LE/DM1, Ch4 (green) = IDD

Idd consumption:

- Idd (normal operation) = 2.93 mA
- Idd (shutdown condition) = 170 μA

AMG070620170915MT

Figure 24: Auto power-saving feature: first output TON

Conditions:

- Temp. = 25 °C, V_{DD} = 3.3 V, Vin = V_{DD}, VLed = 3.0 V, Iset = 20 mA
- Ch1 (yellow) = CLK, Ch2 (blue) = SDI, Ch3 (purple) = LE/DM1, Ch4 (green) = IDD



When the device goes from auto power-saving to normal operating condition, the first output switching ON shows the T_{ON} condition as seen in the plot above.

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8 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

STAP16DPPS05 Package information

8.1 TSSOP24 exposed pad package information

Figure 25: TSSOP24 exposed pad package outline

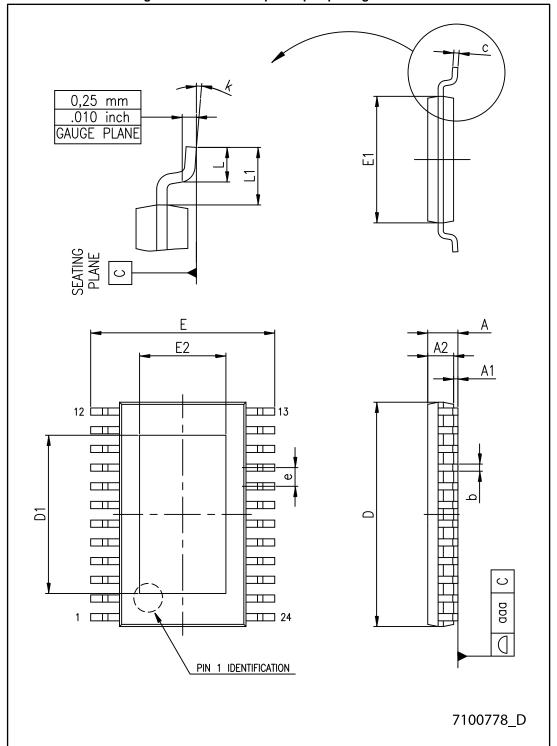


Table 16: TSSOP24 exposed pad mechanical data

Dim	mm			
Dim.	Min.	Тур.	Max.	
А			1.20	
A1			0.15	
A2	0.80	1.00	1.05	
b	0.19		0.30	
С	0.09		0.20	
D	7.70	7.80	7.90	
D1	4.80	5.00	5.2	
Е	6.20	6.40	6.60	
E1	4.30	4.40	4.50	
E2	3.00	3.20	3.40	
е		0.65		
L	0.45	060	0.75	
L1		1.00		
k	0°		8°	
aaa			0.10	

STAP16DPPS05 Package information

8.2 TSSOP24 packing information

Figure 26: TSSOP24 reel outline

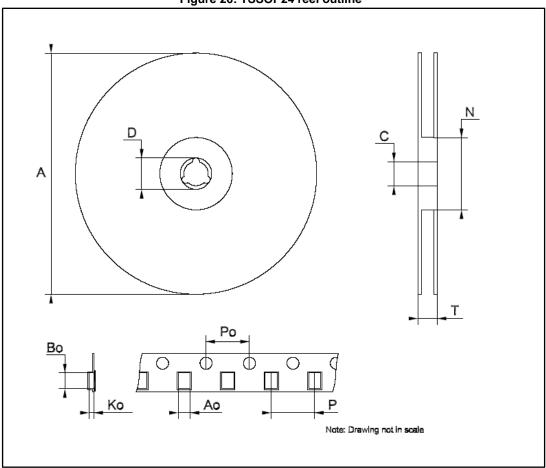


Table 17: TSSOP24 tape and reel mechanical data

Dim.	mm				
Dilli.	Min.	Тур.	Max.		
А		-	330		
С	12.8	-	13.2		
D	20.2	-			
N	60	•			
Т		•	22.4		
Ao	6.8	•	7		
Во	8.2	•	8.4		
Ko	1.7	•	1.9		
Po	3.9	-	4.1		
Р	11.9	-	12.1		

Revision history STAP16DPPS05

9 Revision history

Table 18: Document revision history

Date	Revision	Changes
21-May-2013	1	Initial release.
01-Jul-2013	2	Added footnote in Table 8: Switching characteristics.
11-Oct-2013	3	Modified TOPR value in Table 4: Absolute maximum ratings.
10-Mar-2014	4	Modified footnote 1 in Table 8: Switching characteristics. Added footnote 2 in Table 8: Switching characteristics. Updated Table 1: Pin connections and Table 3: Pin description.
05-Jun-2014	5	Updated Table 16: TSSOP24 exposed pad mechanical data. Minor text changes.
10-Nov-2015	6	Updated features in cover page. Minor text changes.
07-Nov-2017	7	Updated title in cover page. Updated Figure 5: "SDO terminal", Figure 8: "Clock, serial-in, serial-out", Figure 9: "Clock, serial-in, latch, enable, outputs" and Section 8: "Package information". Minor text changes.

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